DESCRIPTION

The SPN3400W is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

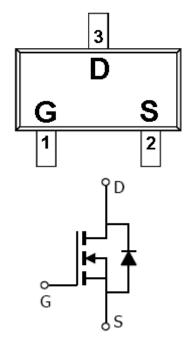
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

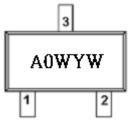
FEATURES

- 30V/5.4A,RDS(ON)= $38m\Omega(@VGS=10V)$
- 30V/4.6A, RDS(ON)= $42m\Omega(@VGS=4.5V)$
- 30V/3.8A,RDS(ON)= $55m\Omega$ @VGS=2.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOT-23-3L package design

PIN CONFIGURATION(SOT-23-3L)



PART MARKING



AOW: Device code

Y: Year W: Week

PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking		
SPN3400WS23RGB	SOT-23-3L	A0W		

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN3400WS23RGB: Tape Reel; Pb − Free; Halogen - Free

ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

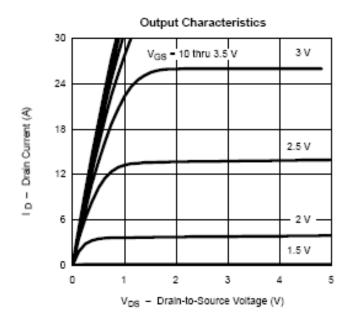
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Dusin Cumant/Ty-150°C	TA=25°C	In	4.5	A	
Continuous Drain Current(T _J =150°C)	Ta=70°C	Id	3.5	A	
Pulsed Drain Current		Ірм	25	A	
Continuous Source Current(Diode Conduction)		Is	1.7	A	
Doman Dissination	Ta=25°C	D-	2.0		
Power Dissipation	Ta=70°C	PD	1.3	W	
Operating Junction Temperature		TJ	150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	90	°C/W	

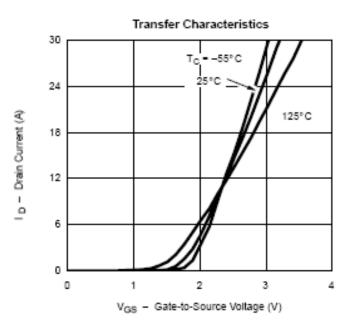
ELECTRICAL CHARACTERISTICS

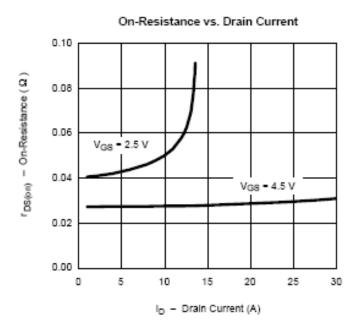
(Ta=25°C Unless otherwise noted)

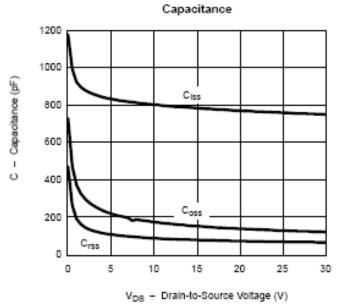
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static			•				
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30				
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.8		1.6	V	
Gate Leakage Current	Igss	V _{DS} =0V,V _{GS} =±12V			±100	nA	
Zero Gate Voltage Drain Current	IDSS	VDS=24V,VGS=1.0V VDS=24V,VGS=0.0V TJ=55°C			1 10	uA	
On-State Drain Current	ID(on)	V _{DS} ≥ 4.5V, V _{GS} =4.5V	10			A	
Drain-Source On-Resistance	RDS(on)	VGS = 10V,ID=5.4A VGS =4.5V,ID=4.6A VGS =2.5V,ID=3.8A		0.030 0.034 0.040	0.038 0.042 0.055	Ω	
Forward Transconductance	gfs	VDS=4.5V,ID=5.4A		12		S	
Diode Forward Voltage	Vsd	Is=1.7A,VGS=0V		0.8	1.2	V	
Dynamic			•				
Total Gate Charge	Qg			10	18	nC	
Gate-Source Charge	Qgs	VDS=15VGS=10V ID=6.7A		1.6			
Gate-Drain Charge	Qgd	-ID-0.7A		3.2			
Input Capacitance	Ciss	V _{DS} =15V _{GS} =0V f=1MHz		450		pF	
Output Capacitance	Coss			240			
Reverse Transfer Capacitance	Crss			38			
Turn-On Time	td(on)			7	15	nS	
	tr	VDD=15RL=15		10	20		
Turn-Off Time	td(off)	$I_D=1.0A, V_{GEN}=10$ $R_G=6\Omega$		20	40		
	tf			11	20		

TYPICAL CHARACTERISTICS

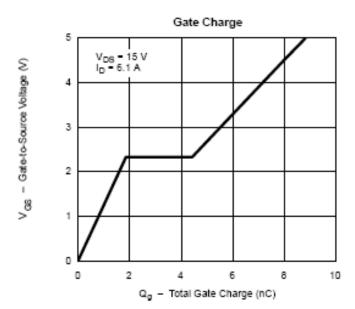


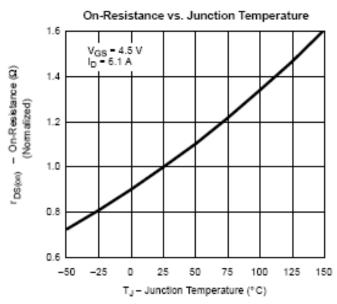


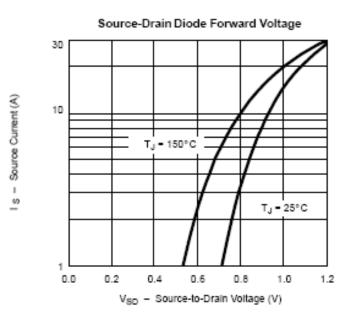


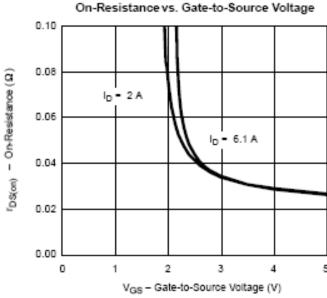


TYPICAL CHARACTERISTICS

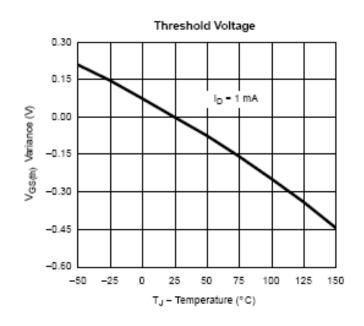


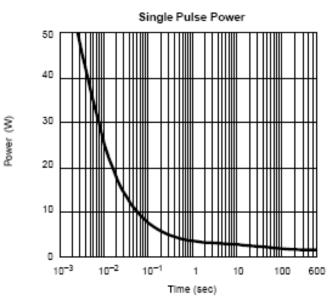


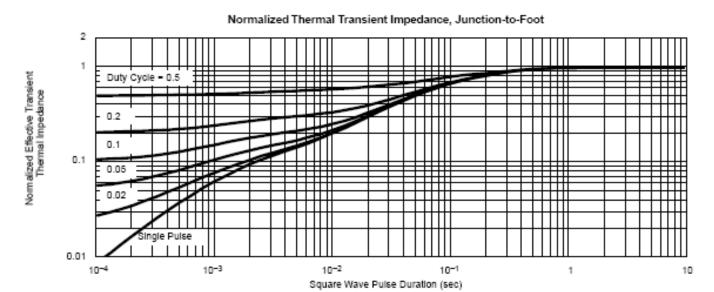




TYPICAL CHARACTERISTICS







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